



5SSB

Old part no. S 830

Silicon Surge Voltage Suppressor

Properties

- § Diffused pnp – Si structure
- § hermetically sealed in metal-ceramic package
- § Available to protect power devices (thyristors) against small and medium power surges (e.g. 200 kW over 10 μ s)

Applications

- § Traction, HVDC transmission, generator excitation,
- § transmitter power supply, high power motor controls

Mechanical Data

M_u	Mounting torque	3.5 Nm
m	Weight	115 g
D_s	Surface creepage distance	11 mm
D_a	Air strike distance	11 mm

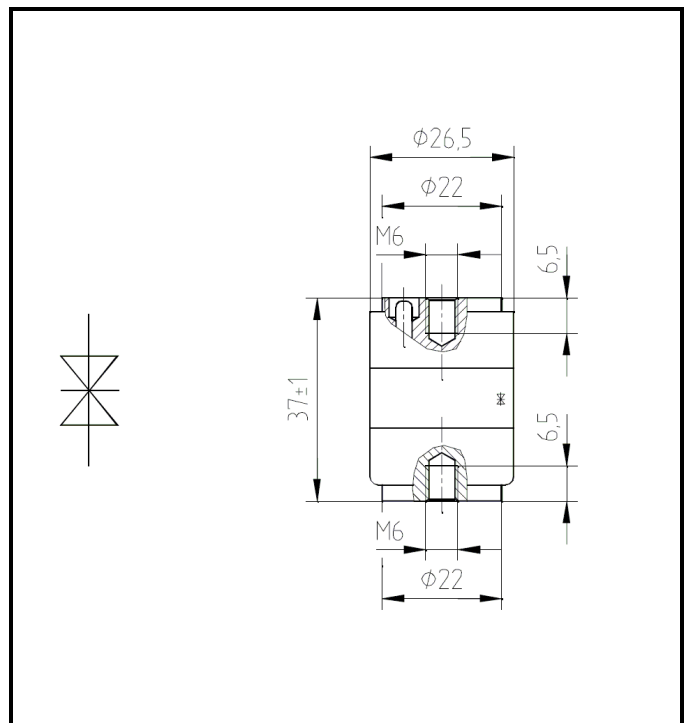


Fig. 1 Case



ABB s.r.o.

Novodvorska 1768/138a, 142 21 Praha 4, Czech Republic

tel.: +420 261 306 250, <http://www.abb.com/semiconductors>

type	Old part no.	V_R (V)	Thyristor V_{DRM} (V) V_{RRM} (V)	I_{RM} (A) for base width				I_{RRM} (A)	P_{RAV} (W)	P_{RSM} (kW)
				$1 \times 10 \mu s$	$1 \times 100 \mu s$	$1 \times 1 ms$	$1 \times 10 ms$			
5SSB 50X0400	S 830-500-04	450 ± 50	500	500	135	33	7.5	70	30*	350
5SSB 50X0500	S 830-500-05	550 ± 50	600	500	135	33	7.5	70	30*	350
5SSB 38X0600	S 830-380-06	650 ± 50	700	380	100	25	4.5	60	30*	350
5SSB 38X0700	S 830-380-07	750 ± 50	800	380	100	25	4.5	60	30*	350
5SSB 30X0800	S 830-300-08	850 ± 50	900	300	80	21	4	50	30*	350
5SSB 30X0900	S 830-300-09	950 ± 50	1000	300	80	21	4	50	30*	350
5SSB 26X1000	S 830-260-10	1050 ± 50	1100	260	67	18	3.6	41	30*	350
5SSB 26X1100	S 830-260-11	1150 ± 50	1200	260	67	18	3.6	41	30*	350
5SSB 23X1200	S 830-230-12	1250 ± 50	1300	230	58	15	3.4	35	30*	350
5SSB 23X1300	S 830-230-13	1350 ± 50	1400	230	58	15	3.4	35	30*	350
5SSB 20X1400	S 830-200-14	1450 ± 50	1500	200	50	13	3	30	30*	350
5SSB 20X1500	S 830-200-15	1550 ± 50	1600	200	50	13	3	30	30*	350
5SSB 30X1600	S 830-300-16	1650 ± 50	1700	300	80	21	4	50	60**	700
5SSB 30X1700	S 830-300-17	1750 ± 50	1800	300	80	21	4	50	60**	700
5SSB 30X1800	S 830-300-18	1850 ± 50	1900	300	80	21	4	50	60**	700
5SSB 30X1900	S 830-300-19	1950 ± 50	2000	300	80	21	4	50	60**	700
5SSB 26X2000	S 830-260-20	2050 ± 50	2100	260	67	18	3.6	41	60**	700
5SSB 26X2100	S 830-260-21	2150 ± 50	2200	260	67	18	3.6	41	60**	700
5SSB 26X2200	S 830-260-22	2250 ± 50	2300	260	67	18	3.6	41	60**	700
5SSB 26X2300	S 830-260-23	2350 ± 50	2400	260	67	18	3.6	41	60**	700
5SSB 23X2400	S 830-230-24	2450 ± 50	2500	230	58	15	3.4	35	60**	700
5SSB 23X2500	S 830-230-25	2550 ± 50	2600	230	58	15	3.4	35	60**	700
5SSB 23X2600	S 830-230-26	2650 ± 50	2700	230	58	15	3.4	35	60**	700
5SSB 23X2700	S 830-230-27	2750 ± 50	2800	230	58	15	3.4	35	60**	700
5SSB 20X2800	S 830-200-28	2850 ± 50	2900	200	50	13	3	30	60**	700
5SSB 20X2900	S 830-200-29	2950 ± 50	3000	200	50	13	3	30	60**	700

Notes:

V_R ... Symmetrical avalanche voltage at $I_A = 20 A$, $t_p = 10 \mu s$, $T_{vj} = 60^\circ C$

I_{RM} ... Max. avalanche current for a single sine half wave pulse

I_{RRM} ... Max. avalanche current for 10 pulses of $100 \mu s$ width, repetition frequency 50 Hz

P_{RAV} ... Admissible continuous losses at $R_{thja} < 1 KW$, $T_a < 60^\circ C$, * single side / ** double side cooling

P_{RSM} ... peak power losses for a single $10 \mu s$ current surge

T_{vj} ... the initial virtual junction temperature is $60^\circ C$

ABB s.r.o., Novodvorska 1768/138a, 142 21 Praha 4, Czech Republic

ABB s.r.o. reserves the right to change the data contained herein at any time without notice

Maximum Ratings		Maximum Limits	Unit
$T_{jmin} - T_{jmax}$	Operating temperature range	-40 ÷ 125	°C
T_{STG}	Storage temperature range	-40 ÷ 125	°C
	Admissible acceleration (vibration)	10	m/s ²

Characteristics for types 5SSB 50X0400 .. 5SSB 20X1500		Value		Unit
		<i>typ</i>	<i>max</i>	
V_R	Dependence of avalanche voltage V_R on junction temperature <i>Note 1</i>	$V_R(T) = V_{R0}[1 + 1.1 \times 10^{-3}(T - 60 \text{ °C})]$		V
C_j	Junction capacitance $V_R = 0 \text{ V}, T_j = 60 \text{ °C}$	1 100		pF
R_{thjh}	Thermal resistance junction to heatsink <i>Note 2</i>		0.5	K/W

Characteristics for types 5SSB 30X1600 .. 5SSB 20X3100		Value		Unit
		<i>typ</i>	<i>max</i>	
V_R	Dependence of avalanche voltage V_R on junction temperature <i>Note 1</i>	$V_R(T) = V_{R0}[1 + 1.1 \times 10^{-3}(T - 60 \text{ °C})]$		V
C_j	Junction capacitance $V_R = 0 \text{ V}, T_j = 60 \text{ °C}$	550		pF
R_{thjh}	Thermal resistance junction to heatsink		0.25	K/W

Note 1: $V_R(60\text{°C}) = V_{R0}$; $V_R(25\text{°C}) = 0,96 \times V_{R0}$; $V_R(125\text{°C}) = 1,07 \times V_{R0}$

Note 2: For single sided cooling the side carrying the serial number shall be cooled.

Notes: